## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent Application

tant Commissioner for Patents

**运动**证gton, D.C. 20231

O Re:

Inventor(s): Janardhanan Anand Subramony, Yoshitaka Yokota, Ramaseshan Suryanarayanan Iyer,

Lee Luo, Aihua Chen

Title: METHODS FOR SILICON OXIDE AND OXYNITRIDE DEPOSITION USING SINGLE WAFER LOW PRESSURE

CVD

Transmitted herewith is the patent application identified above, including:

- X Specification, claims and abstract, totaling <u>35 pages</u>.
- X Drawings totaling 15 pages, Formal X Informal.
- X Unsigned Declaration and Power of Attorney.

Assignment of the invention to **Applied Materials**, Inc.

Information Disclosure Statement (IDS)/PTO-1449 with copies of IDS citations.

Check No. 47170 in the amount of \$1370.00

Fee Items	Claims Filed	Included With Basic Fee	Extra Claims	Fee Rate	Total	
Total Claims	27	- 20 =	7	X \$18.00	126.00	
independent Claims	9	- 3 =	6	X \$84.00	504.00	
Basic Filing Fee \$740.00						

The Commissione	r is hereby an	thorized to cha	rge \$( ) to	o Depos	sit Account l	No. 50-1	1074.

- XX The Commissioner is hereby authorized to charge any additional fees which may be required, or credit any overpayment to Deposit Account No. <u>02-2666</u>. A duplicate copy of this transmittal is enclosed.
- XX Please address all future correspondence to:

PATENT COUNSEL

APPLIED MATERIALS, INC. Legal Affairs Department

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I hereby certify that this correspondence is being deposited with the United States Postal Service as express mail in an envelope addressed to: Box Patent Application, Assistant Commissioner for Patents, Washington, D C. 20231.

Respectfully submitted,

Express Mail Receipt No EL867648876US

Date of Deposit Persper 28, 2001

December 28, 200

Signature Michelle Beg.

Michael A. Bernadicou Registration No. 35,934